

Ultra low current consumption SPDT switch

■FEATURES

- Low control voltage 1.6 V min.
- Low current consumption 0.1 µA typ.
- Low insertion loss
 0.45 dB typ. @ f = 920 MHz
 0.50 dB typ. @ f = 2.4 to 2.5 GHz
- High isolation
 30 dB typ. @ f = 920 MHz
 22 dB typ. @ f = 2.4 to 2.5 GHz
- High linearity
 - P_{-0.1dB} = +30 dBm typ. @ f = 920 MHz, 2.4 to 2.5 GHz
- Small package 1.0 mm x 1.0 mm, t = 0.375 mm
- RoHS compliant and Halogen Free, MSL1

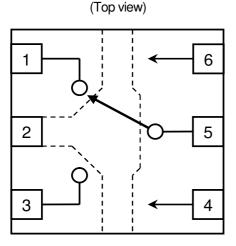
■APPLICATION

• LPWA (SIGFOX, LoRaWAN, Wi-SUN) applications

• 2.4 GHz Wireless LAN (802.11b/g/n/ax), Bluetooth

•Antenna switching, path switching, general purpose switching applications

BLOCK DIAGRAM (DFN6-75)



■GENERAL DESCRIPTION

The NJG1816K75 is a 2-bit control SPDT switch with 0.1 μ A ultra-low current consumption.

The NJG1816K75 features high linearity and low insertion loss at 1.8 V operating voltage up to 3 GHz. This switch is suitable for wireless communication devices with low power consumption such as wearable and mobile terminals.

The small and thin package of DFN6-75 offers small mounting area.

■FUNCTIONAL DESCRIPTION

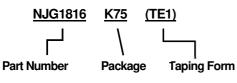
"H" = V_{CTL}(H), "L" = V_{CTL}(L)

ON Path	VCTL1	VCTL2
PC-P1	L	н
PC-P2	Н	L

■PIN CONFIGURATION

PIN NO.	SYMBOL	DESCRIPTION	
1	P1	RF terminal	
2	NC(GND)	Ground terminal	
3	P2	RF terminal	
4	VCTL2	Control signal input terminal	
5	PC	RF terminal	
6	VCTL1	Control signal input terminal	

■ PRODUCT NAME INFORMATION



ORDERING INFORMATION

PART NUMBER	PACKAGE OUTLINE	RoHS	HALOGEN- FREE	TERMINAL FINISH	MARKING	WEIGHT (mg)	MOQ (pcs.)
NJG1816K75	DFN6-75	Yes	Yes	Ni/Pd/Au	5	1.2	5,000

■ ABSOLUTE MAXIMUM RATINGS

$T_a = 25^{\circ}C, Z_s = Z_l = 5$					
PARAMETER	SYMBOL	RATINGS	UNIT		
RF input power ⁽¹⁾	P _{IN}	+30	dBm		
Control voltage	V _{CTL}	4.5	V		
Power dissipation (2)	PD	380	mW		
Operating temperature	T _{opr}	-40 to +105	°C		
Storage temperature	T _{stg}	-55 to +150	°C		

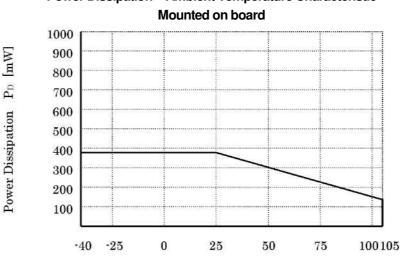
(1): $V_{CTL}(L) = 0 V$, $V_{CTL}(H) = 1.8 V$, on state port

(2): Mounted on four-layer FR4 PCB with through-hole (76.2 \times 114.3 mm), T_i = 150 °C

■ POWER DISSIPATION VS.AMBIENT TEMPERATURE

Please, refer to the following Power Dissipation and Ambient Temperature.

(Please note the surface mount package has a small maximum rating of Power Dissipation [PD], a special attention should be paid in designing of thermal radiation.)



Power Dissipation – Ambient Temperature Characteristic

Ambient Temperature Ta [°C]

■ ELECTRICAL CHARACTERISTICS (DC CHARACTERISTICS)

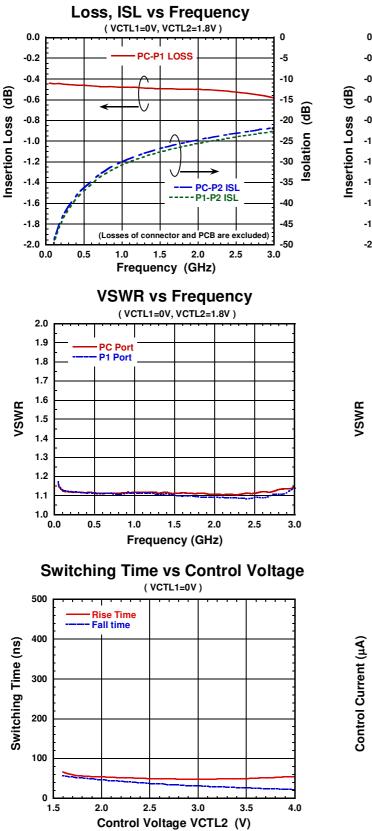
$V_{CTL}(H) = 1.8 V$, $V_{CTL}(L) = 0 V$, $T_a = 25^{\circ}C$, $Z_s = Z_l = 50 \Omega$, with application circuit						
PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Control voltage (HIGH)	V _{CTL} (H)	VCTL1, VCTL2 terminal	1.6	1.8	4.0	V
Control voltage (LOW)	V _{CTL} (L)	VCTL1, VCTL2 terminal	-0.2	-	0.2	V
Control current	ICTL		-	0.1	2.0	μA

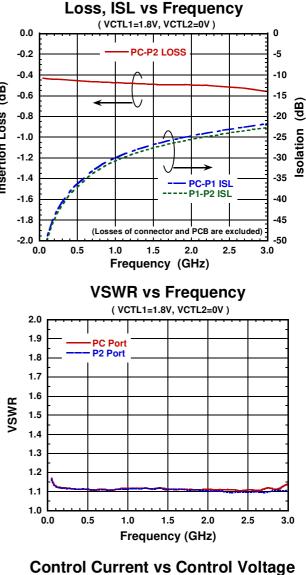
■ ELECTRICAL CHARACTERISTICS (RF CHARACTERISTICS)

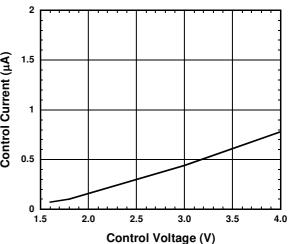
VCTL(H) = 1.8 V, VCTL(L) = 0 V, Ta = 25°C, Zs = ZI = 50 Ω , with application circuit

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Incortion loss	LOSS	f = 920 MHz	-	0.45	0.65	dD
Insertion loss	1055	f = 2.4 to 2.5 GHz	-	0.50	0.70	dB
lociation		f = 920 MHz	26	30	-	٩D
Isolation	ISL	f = 2.4 to 2.5 GHz	18	22	-	dB
Input power at 0.1 dB	P-0.1dB	f = 920 MHz	+25	+30	-	dDm
compression point		f = 2.4 to 2.5 GHz	+25	+30	-	dBm
Input power at 1 dB	P-1dB	f = 920 MHz	+28	+30	-	dDire
compression point		f = 2.4 to 2.5 GHz	+28	+30	-	dBm
VSWR		f = 920 MHz	-	1.1	1.4	
	VSWR	f = 2.4 to 2.5 GHz	-	1.2	1.4	-
Switching time	Tsw	50% V _{CTL} to 10%/90% RF	-	100	300	ns

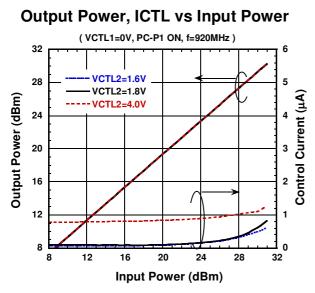
ELECTRICAL CHARACTERISTICS



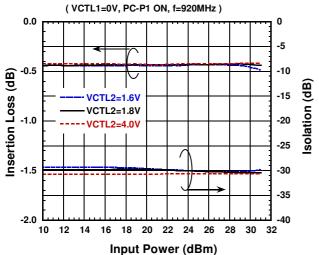




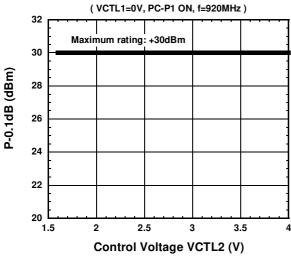
■ ELECTRICAL CHARACTERISTICS



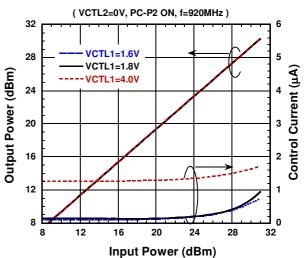
Insertion Loss, Isolation vs Input Power



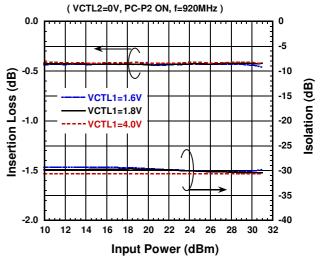




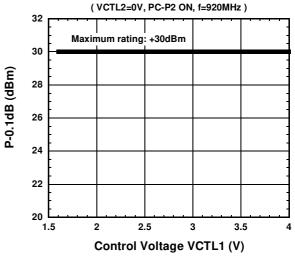
Output Power, ICTL vs Input Power



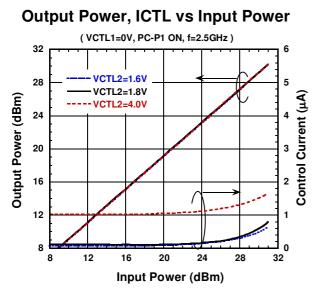
Insertion Loss, Isolation vs Input Power



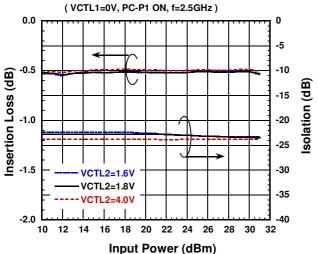
P-0.1dB vs Control Voltage



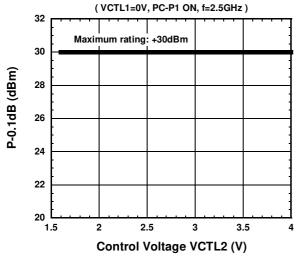
■ ELECTRICAL CHARACTERISTICS



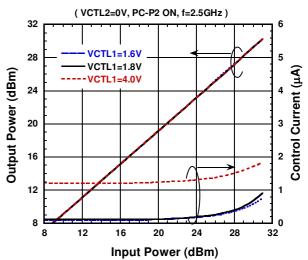




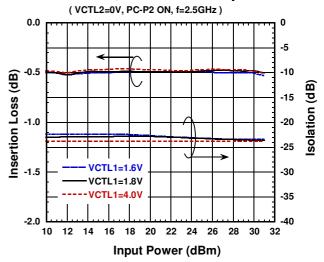




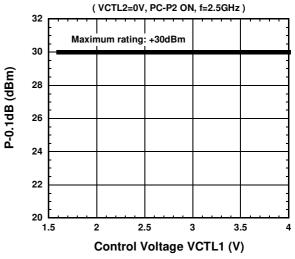
Output Power, ICTL vs Input Power



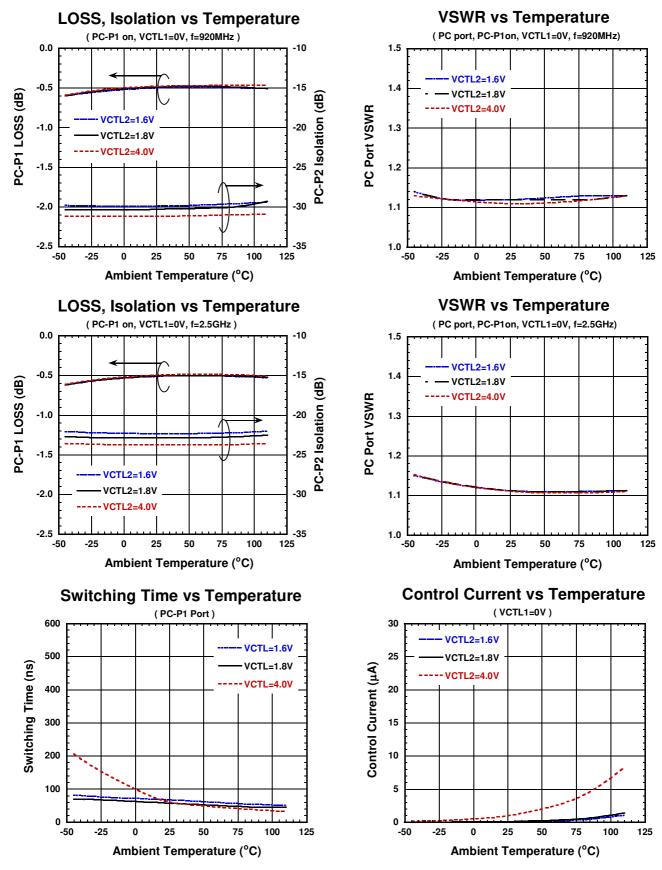
Insertion Loss, Isolation vs Input Power



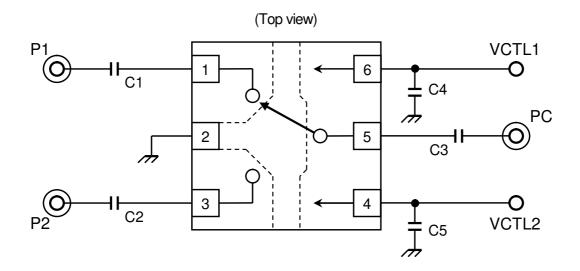
P-0.1dB vs Control Voltage



■ ELECTRICAL CHARACTERISTICS



■ APPLICATION CIRCUIT



■ PARTS LIST

Part ID	Value	Notes
C1 to C3	1000 pF	MURATA (GRM03)
C4 to C5	10 pF	MURATA (GRM03)

NJG1816K75

P2

PC

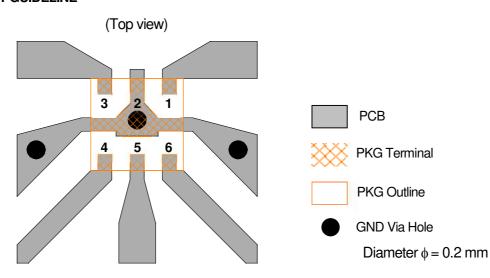
Losses of PCB and connectors	Ta = -	-25°C
	, ia – i	-20 0

Frequency (MHz)	Loss (dB)
920	0.22
2400	0.42
2500	0.42

PCB: FR-4 t = 0.2 mm MICROSTRIP LINE WIDTH: 0.4 mm (Zo = 50 Ω) PCB SIZE: 19.4 x 14.0 mm

■ PCB LAYOUT GUIDELINE

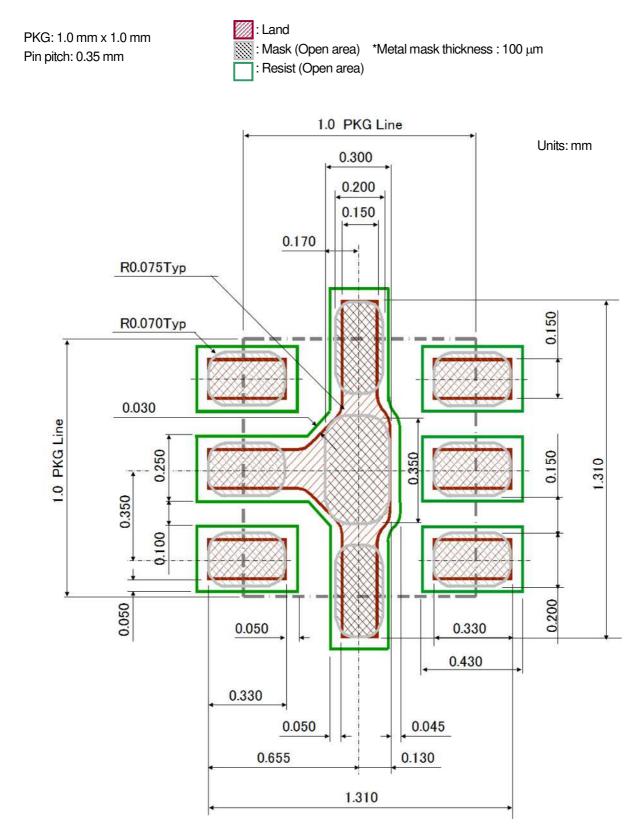
EVALUATION BOARD



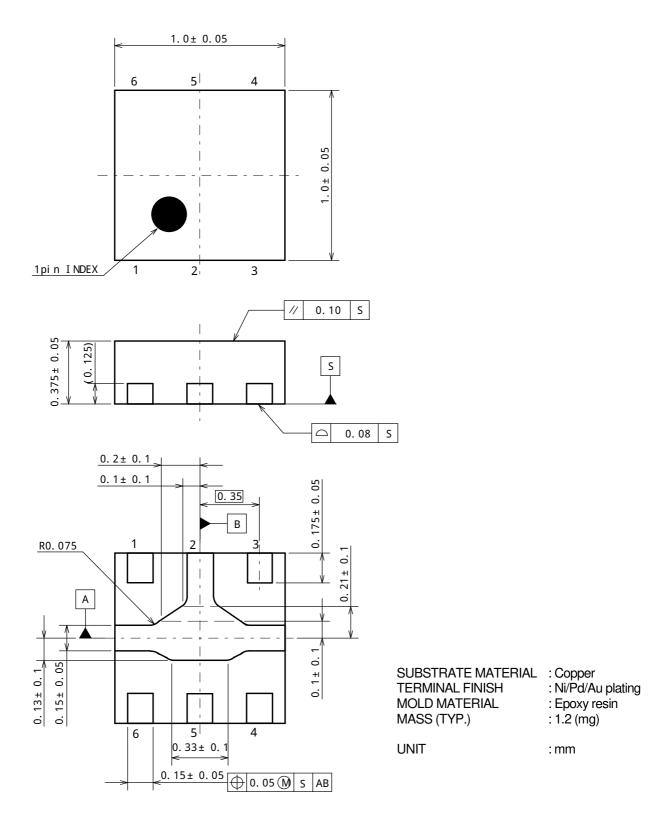
PRECAUTIONS

- [1] The DC blocking capacitors (C1, C2, C3) should be placed at RF terminals. Please choose appropriate capacitance value at the application frequency.
- [2] For avoiding the degradation of RF performance, the bypass capacitors (C4, C5) should be placed as close as possible to VCTL terminals.
- [3] For good RF performance, exposed pad should be connected to PCB ground plane of substrate, and through –holes should be placed near the IC.

■ RECOMMENDED FOOTPRINT PATTERN (DFN6-75)

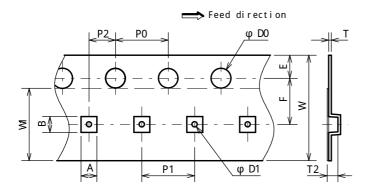


■ PACKAGE OUTLINE (DFN6-75)



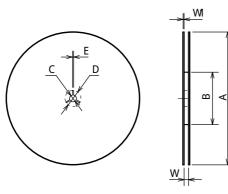
■ PACKING SPECIFICATION (DFN6-75)

TAPING DIMENSIONS



SYMBOL	DI MENSI ON	REMARKS
А	1. 19 ^{+0.04}	BOTTOM DI MENSI ON
В	1. 19 ^{+0.04}	BOTTOM DI MENSI ON
D0	1.5 ^{+0.1}	
D1	0.5± 0.05	
Е	1.75± 0.1	
F	3.5± 0.05	
P0	4.0± 0.1	
P1	4.0± 0.1	
P2	2.0± 0.05	
Т	0. 18± 0. 05	
T2	0.69± 0.1	
W	8.0± 0.1	
WI	5. 5± 0. 1	THICKNESS 60µ max

REEL DIMENSIONS

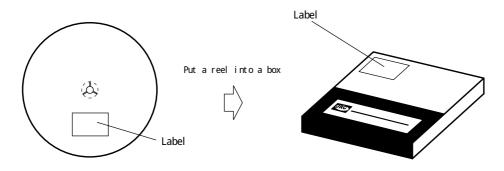


SYMBOL	DI MENSI ON
Α	φ 180 _3
В	φ 60 ⁺¹ ₀
С	φ 13± 0.2
D	φ 21± 0.8
E	2± 0.5
W	9± 0.3
W1	1. 2

TAPING STATE

Insert direction	<mark>< Sea</mark>	ling with covering ta	pe >	
(TE1)				
Feed di rect i on	Empty tape	Devi ces 5000pcs/reel	Empty tape 150 to 200mm	<pre>Covering tape 600 to 800nmn</pre>

PACKING STATE



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 - Traffic control system
 - Combustion equipment

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 - 8-1. Quality Warranty Period

In the case of a product purchased through an authorized distributor or directly from us, the warranty period for this product shall be one (1) year after delivery to your company. For defective products that occurred during this period, we will take the quality warranty measures described in section 8-2. However, if there is an agreement on the warranty period in the basic transaction agreement, quality assurance agreement, delivery specifications, etc., it shall be followed.

8-2. Quality Warranty Remedies

When it has been proved defective due to manufacturing factors as a result of defect analysis by us, we will either deliver a substitute for the defective product or refund the purchase price of the defective product.

- Note that such delivery or refund is sole and exclusive remedies to your company for the defective product.
- 8-3. Remedies after Quality Warranty Period

With respect to any defect of this product found after the quality warranty period, the defect will be analyzed by us. On the basis of the defect analysis results, the scope and amounts of damage shall be determined by mutual agreement of both parties. Then we will deal with upper limit in Section 8-2. This provision is not intended to limit any legal rights of your company.

- 9. Anti-radiation design is not implemented in the products described in this document.
- 10. The X-ray exposure can influence functions and characteristics of the products. Confirm the product functions and characteristics in the evaluation stage.
- 11. WLCSP products should be used in light shielded environments. The light exposure can influence functions and characteristics of the products under operation or storage.
- 12. Warning for handling Gallium and Arsenic (GaAs) products (Applying to GaAs MMIC, Photo Reflector). These products use Gallium (Ga) and Arsenic (As) which are specified as poisonous chemicals by law. For the prevention of a hazard, do not burn, destroy, or process chemically to make them as gas or power. When the product is disposed of, please follow the related regulation and do not mix this with general industrial waste or household waste.
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